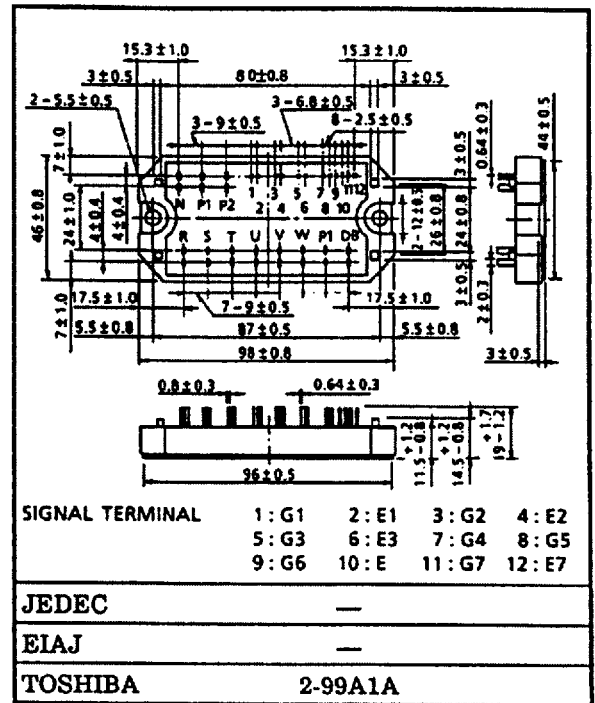


### High Power Switching Applications

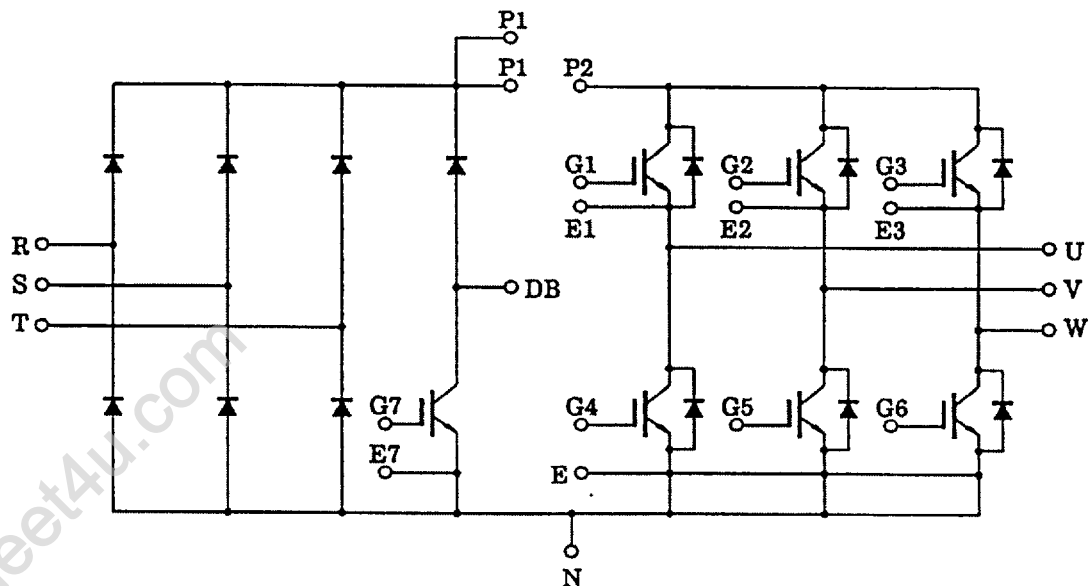
#### Motor Control Applications

- Integrates Inverter, Converter and Brake Power Circuits in One Package.
- Output (Inverter Stage)
  - : 3 $\phi$ 15A/1200V High Speed Type IGBT
  - $V_{CE(sat)}$  = 4.00V (Max.)
  - $t_f$  = 0.30 $\mu$ s (Max.)
  - $t_{rr}$  = 0.15 $\mu$ s (Max.)
- Input (Converter Stage)
  - : 3 $\phi$ 15A/1600V Silicon Rectifier
  - $V_F$  = 1.20V (Max.)
- Brake Stage
  - : 8A/1200V IGBT & 8A/1200V FRD
- The Electrodes are Isolated from Case.



Weight : 175g

### Equivalent Circuit



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**MIG15Q901H**

**Maximum Ratings (Ta = 25°C)**

STAGE	CHARACTERISTIC		SYMBOL	RATINGS	UNIT	
Inverter	Collector-Emitter Voltage		$V_{CES}$	1200	V	
	Gate-Emitter Voltage		$V_{GES}$	±20	V	
	Collector Current	DC	$I_C$	15	A	
		1ms	$I_{CP}$	30		
	Forward Current	DC	$I_F$	15	A	
		1ms	$I_{FM}$	30		
Collector Power Dissipation (Tc = 25°C)			$P_C$	125	W	
Converter	Repetitive Peak Reverse Voltage		$V_{RRM}$	1600	V	
	Average Output Rectified Current		$I_O$	15	A	
	Peak One Cycle Surge Forward Current (50Hz, Non-Repetitive)		$I_{FSM}$	250	A	
Brake	IGBT	Collector-Emitter Voltage		$V_{CES}$	1200	V
		Gate-Emitter Voltage		$V_{GES}$	±20	V
		Collector Current	DC	$I_C$	8	A
			1ms	$I_{CP}$	16	
	Collector Power Dissipation (Tc = 25°C)			$P_C$	80	W
	FRD	Repetitive Peak Reverse Voltage		$V_{RRM}$	1200	V
		Forward Current	DC	$I_F$	8	A
			1ms	$I_{FM}$	16	
Module		Junction Temperature		$T_j$	150	°C
	Storage Temperature Range		$T_{stg}$	-40 ~ 125	°C	
	Isolation Voltage		$V_{isol}$	2500 (AC 1 minute)	V	
	Screw Torque		—	3	N·m	

**Electrical Characteristics (Ta = 25°C)**

a. Inverter Stage

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Gate Leakage Current		$I_{GES}$	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	±10	μA
Collector Cut-off Current		$I_{CES}$	$V_{CE} = 1200V, V_{GE} = 0$	—	—	1.0	mA
Gate-Emitter Cut-off Voltage		$V_{GE(off)}$	$I_C = 15mA, V_{CE} = 5V$	3.0	—	6.0	V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = 15A, V_{GE} = 15V$	—	3.00	4.00	V
Input Capacitance		$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0$ $f = 1MHz$	—	1850	—	pF
Switching Time	Turn-on Delay Time	$t_{d(on)}$	Inductive Load $V_{CC} = 600V$ $I_C = 15A$ $V_{GE} = \pm 15V$ $R_G = 100\Omega$  (Note 1)	—	0.08	0.16	μs
	Rise Time	$t_r$		—	0.12	0.24	
	Turn-on Time	$t_{on}$		—	0.40	0.80	
	Turn-off Delay Time	$t_{d(off)}$		—	0.30	0.60	
	Fall Time	$t_f$		—	0.20	0.40	
	Turn-off Time	$t_{off}$		—	0.70	1.30	
Forward Voltage		$V_F$	$I_F = 15A, V_{GE} = 0$	—	2.00	2.50	V
Reverse Recovery Time		$t_{rr}$	$I_F = 15A, V_{GE} = -10V$ $di/dt = 100A/\mu s$	—	0.20	0.50	μs
Thermal Resistance		$R_{th(j-c)}$	Transistor	—	—	1.00	°C/W
			Diode	—	—	1.80	

## b. Converter Stage

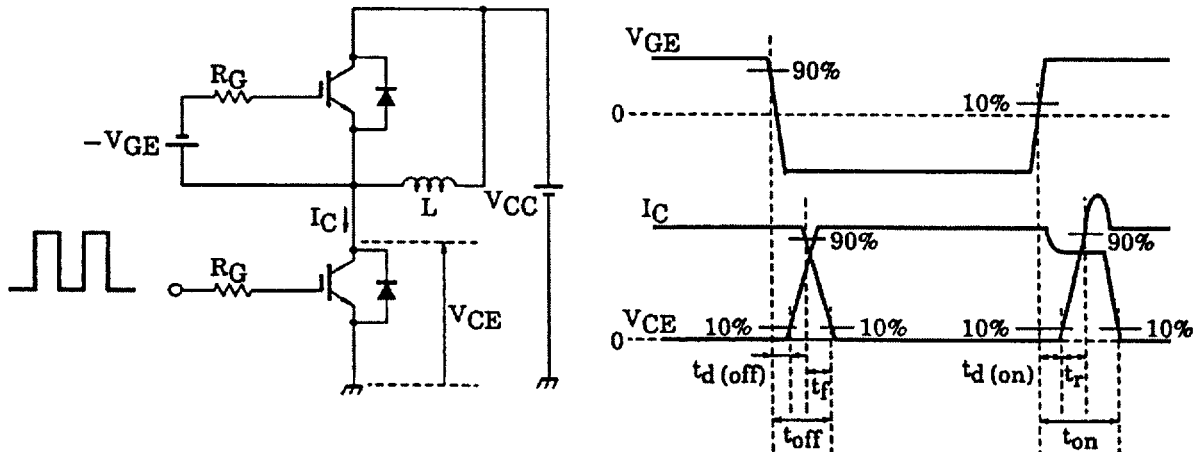
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Repetitive Peak Reverse Current	$I_{RRM}$	$V_{RRM} = 1600V$	-	-	50	$\mu A$
Peak Forward Voltage	$V_{FM}$	$I_{FM} = 15A$	-	1.05	1.20	V
Peak One Cycle Surge Forward Current	$I_{FSM}$	50Hz Sine-half-wave	250	-	-	A
Thermal Resistance	$R_{th(j-c)}$	-	-	-	2.50	$^{\circ}C/W$

**MIG15Q901H**

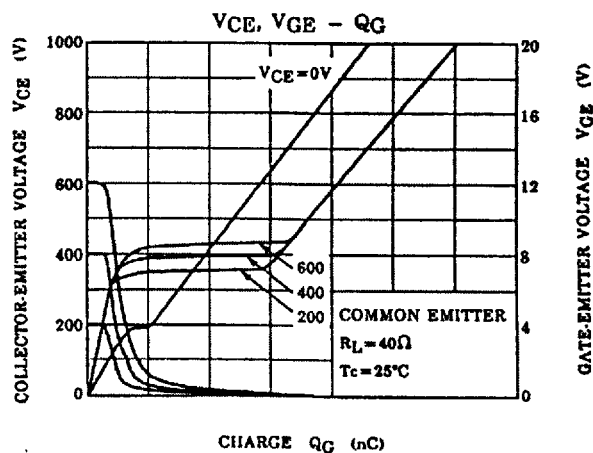
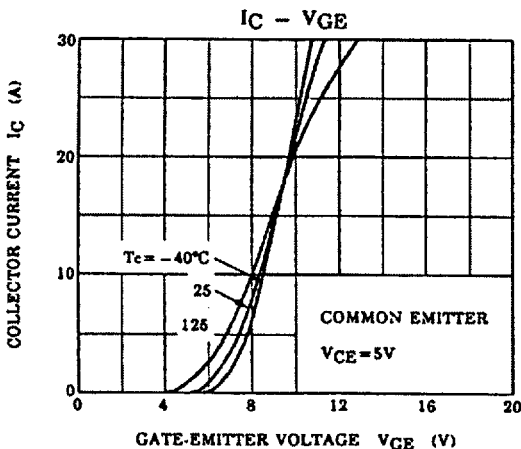
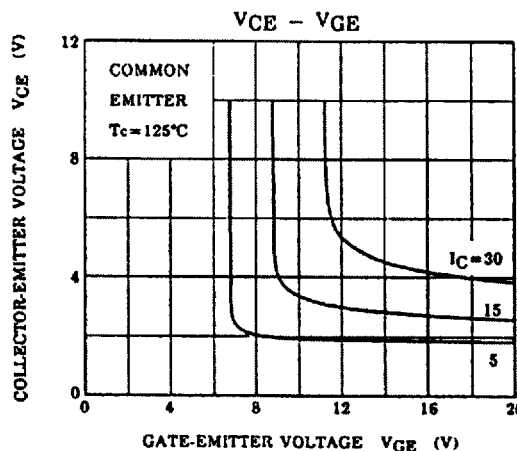
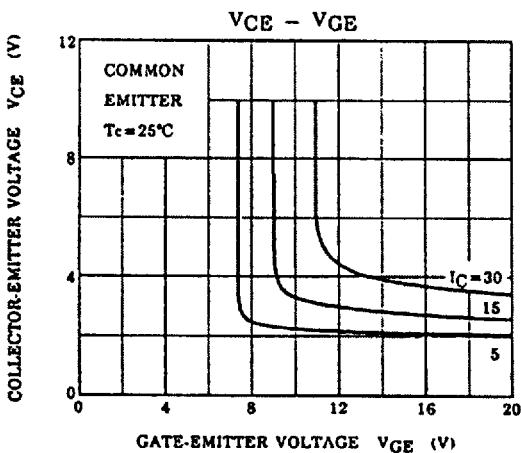
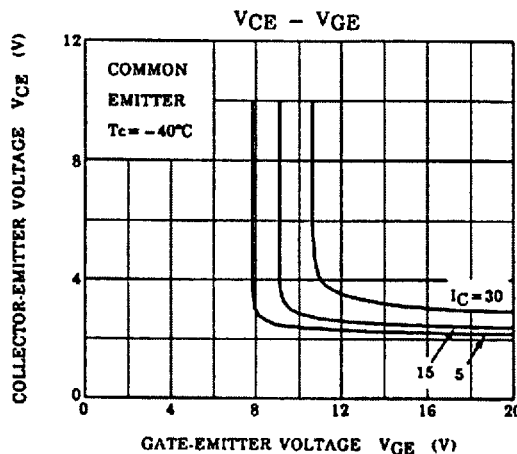
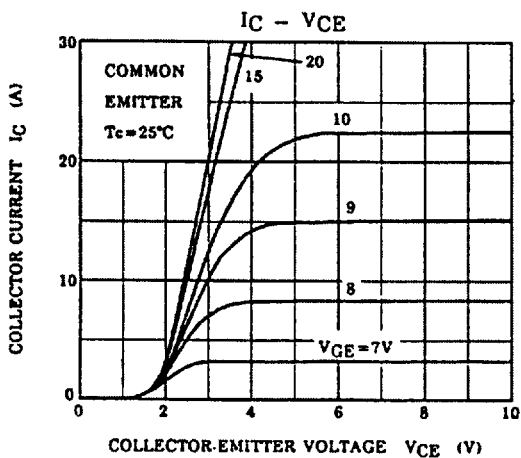
c. Brake Stage

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Gate Leakage Current		$I_{GES}$	$V_{GE} = \pm 20V, V_{CE} = 0$	-	-	$\pm 10$	$\mu A$
Collector Cut-off Current		$I_{CES}$	$V_{CE} = 1200V, V_{GE} = 0$	-	-	1.0	mA
Repetitive Peak Reverse Current		$I_{RRM}$	$V_{RRM} = 1200V$	-	-	1.0	mA
Gate-Emitter Cut-off Voltage		$V_{GE(off)}$	$I_C = 8mA, V_{CE} = 5V$	3.0	-	6.0	V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = 8A, V_{GE} = 15V$	-	3.00	4.00	V
Input Capacitance		$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0$ $f = 1MHz$	-	1000	-	pF
Switching Time	Turn-on Delay Time	$t_{d(on)}$	Inductive Load $V_{CC} = 600V$ $I_C = 8A$ $V_{GE} = \pm 15V$ $R_G = 150\Omega$  (Note 1)	-	0.08	0.16	$\mu s$
	Rise Time	$t_r$		-	0.12	0.24	
	Turn-on Time	$t_{on}$		-	0.40	0.80	
	Turn-off Delay Time	$t_{d(off)}$		-	0.30	0.60	
	Fall Time	$t_f$		-	0.30	0.50	
	Turn-off Time	$t_{off}$		-	0.70	1.30	
Forward Voltage		$V_F$	$I_F = 8A, V_{GE} = 0$	-	1.20	2.50	V
Thermal Resistance		$R_{th(j-c)}$	Transistor	-	-	1.56	$^{\circ}C/W$
			Diode	-	-	1.80	

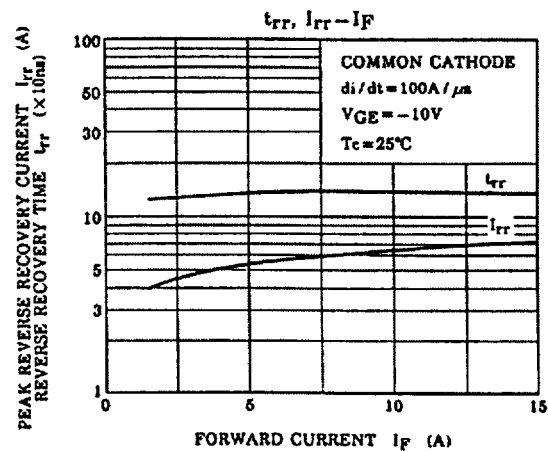
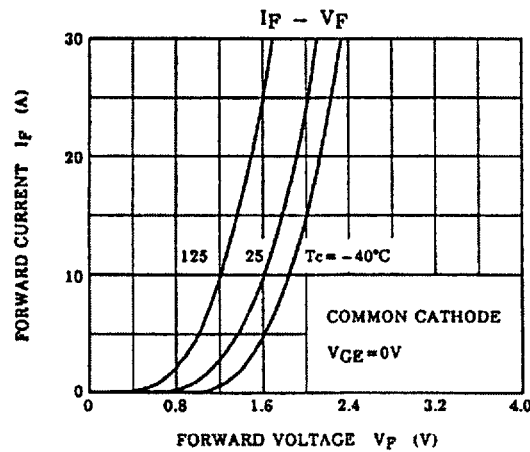
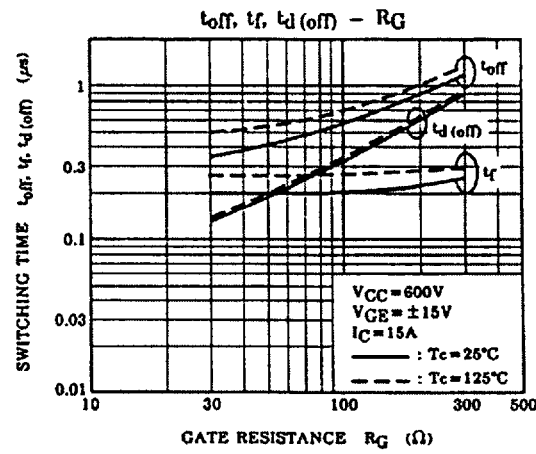
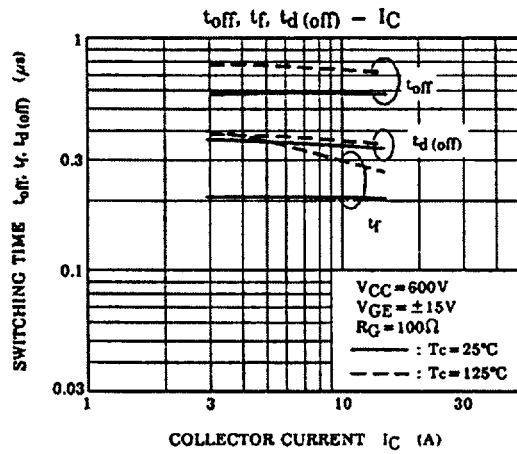
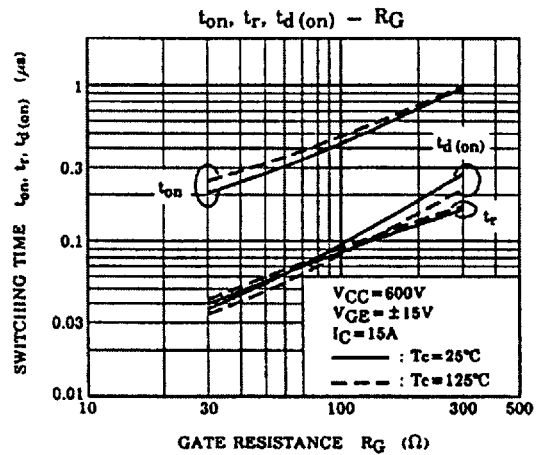
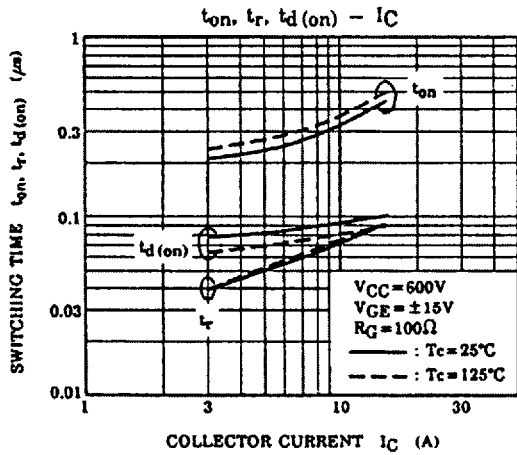
Note. 1 Switching Time Test Circuit & Timing Chart



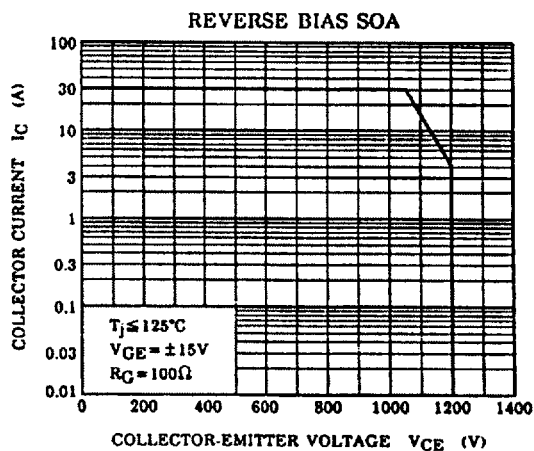
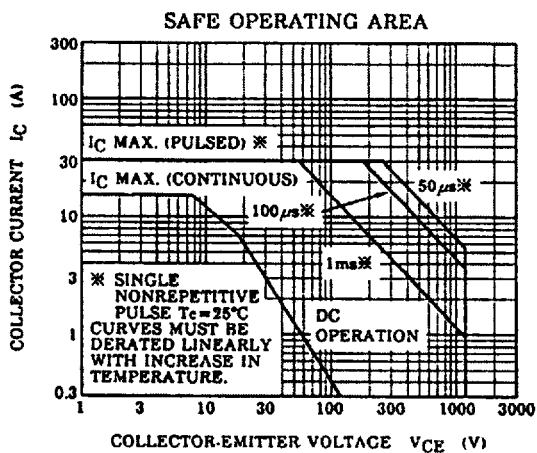
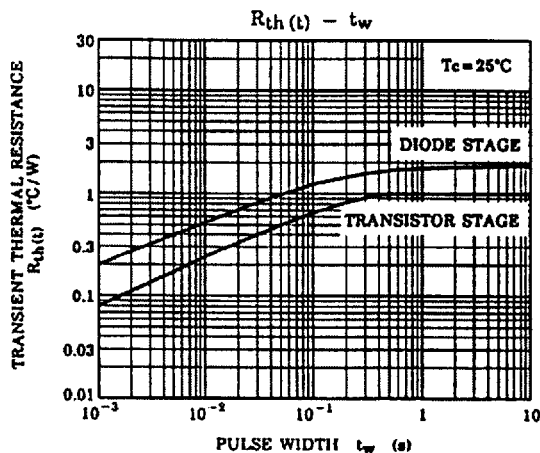
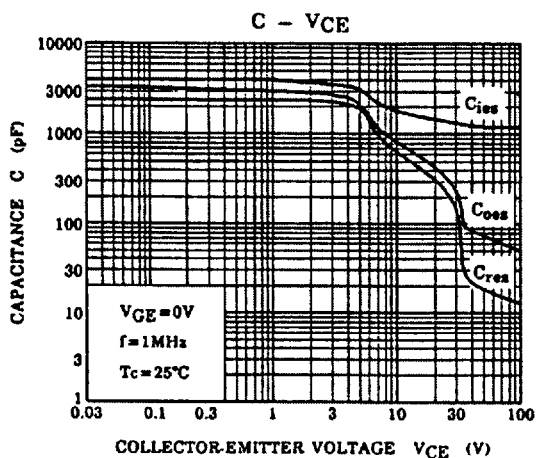
a. Inverter Stage



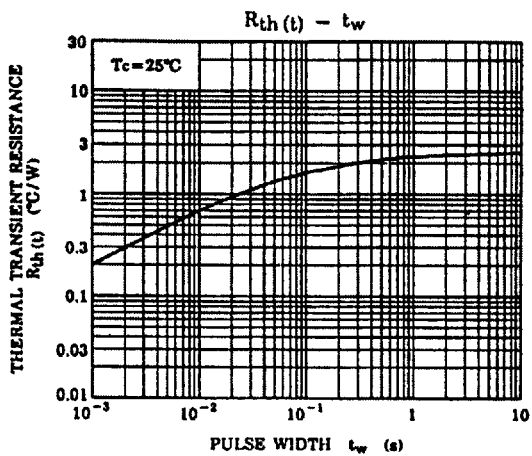
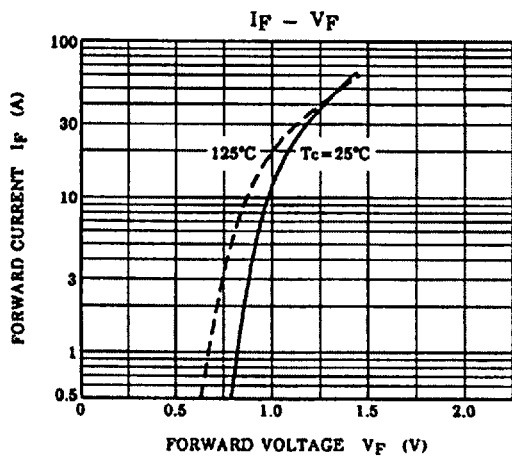
a. Inverter Stage



a. Inverter Stage

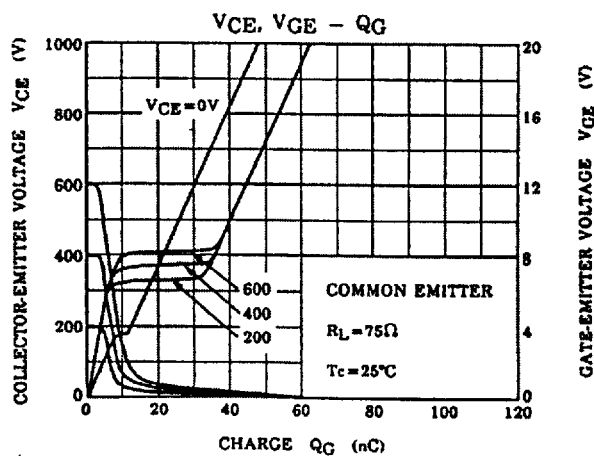
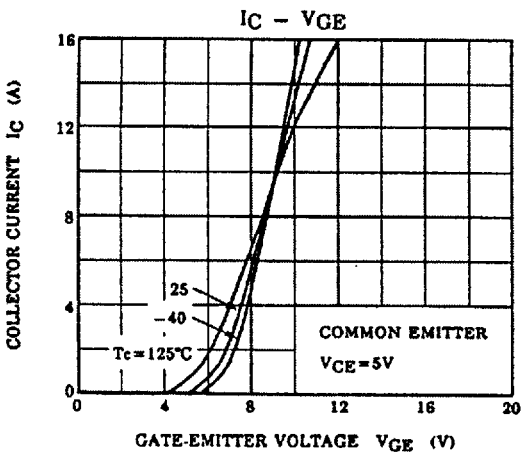
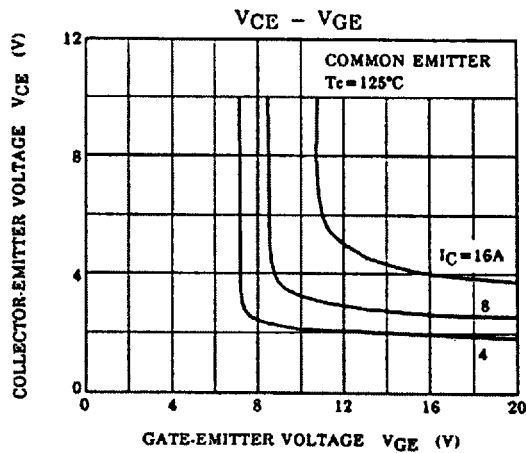
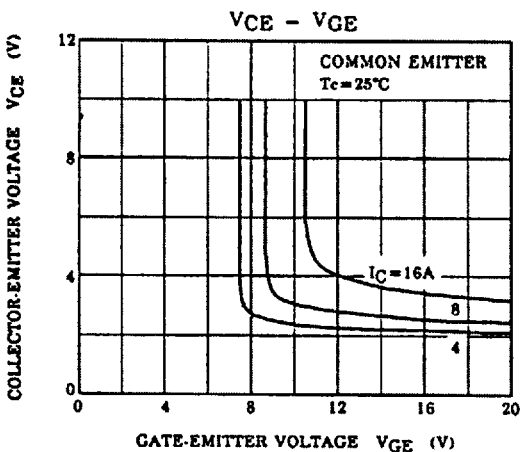
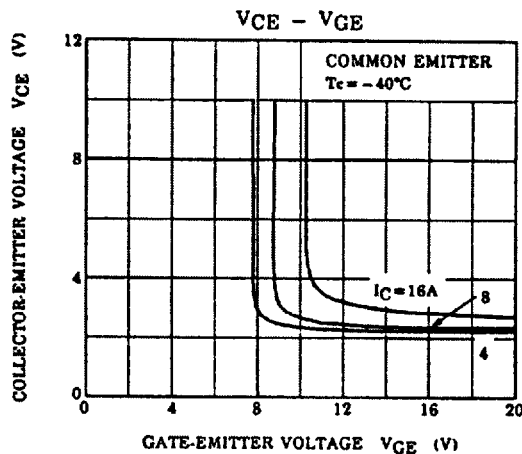
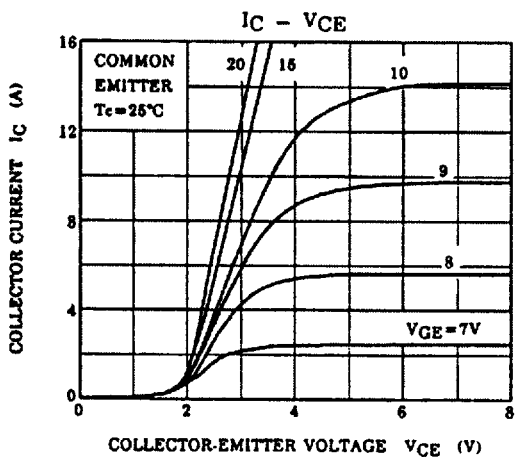


b. Converter Stage



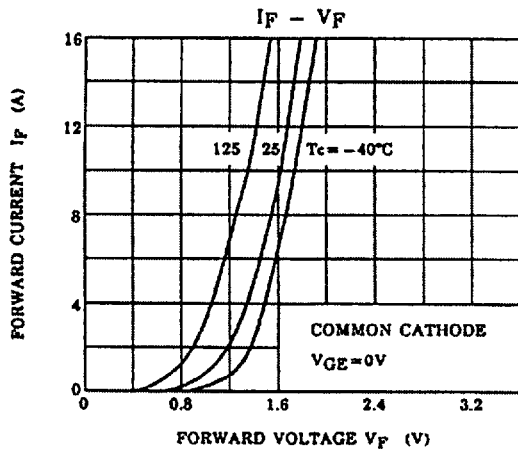
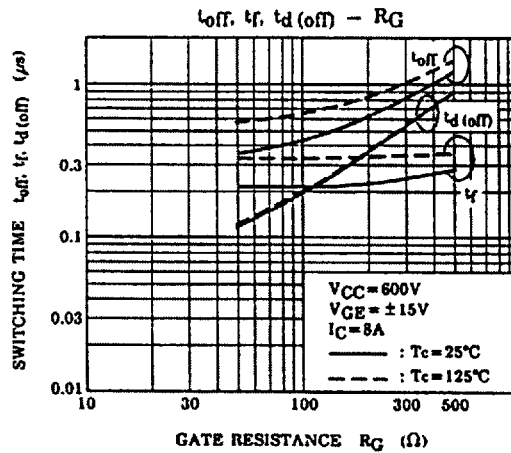
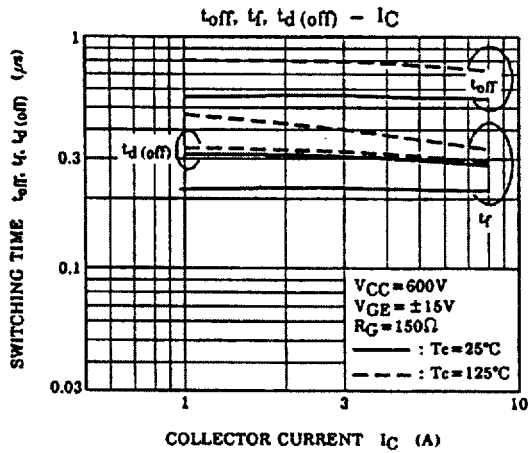
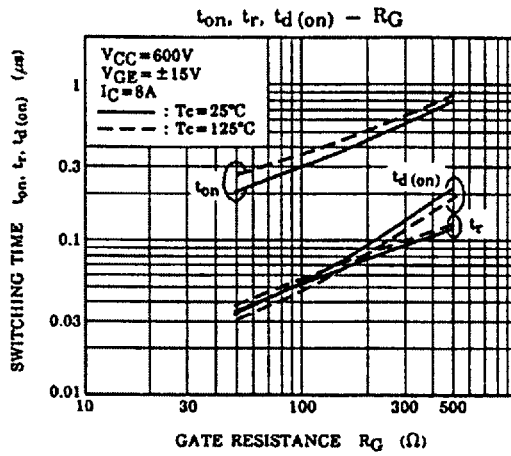
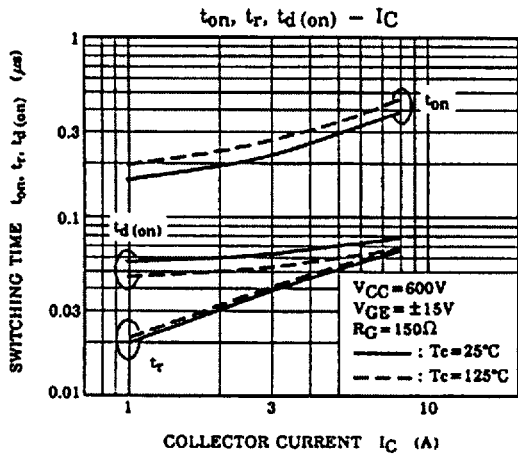


c. Brake Stage



# MIG15Q901H

## c. Brake Stage



c. Brake Stage

